1. General description

Nexperia introduces leading edge Silicon Carbide (SiC) Schottky diode for ultra-high performance, low loss, high efficiency power conversion applications. The SiC Schottky diode is encapsulated in a Real-2-Pin (R2P) TO-220-2 through-hole power plastic package. The product offers temperature independent capacitive turn-off, zero recovery switching behavior combined with an outstanding figure-of-merit ($Q_C \times V_F$). The Merged PiN Schottky (MPS) diode improves the robustness expressed in a high I_{FSM} .

2. Features and benefits

- · Zero forward and reverse recovery
- · Reduced system costs
- · Temperature independent fast and smooth switching performance
- Outstanding figure-of-merit (Q_c x V_F)
- High I_{FSM} capability
- · High power density
- System miniaturization
- Reduced EMI

3. Applications

- Switch Mode Power Supply (SMPS)
- AC-DC and DC-DC converter
- · Battery charging infrastructure
- Server and telecom power supply
- Uninterruptible Power Supply (UPS)
- · Photovoltaic inverters

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit | |
|-----------------|-------------------------|-----------------------------------------------------------------------------------------------------------------------------------------|--|-----|-----|-----|------|--|
| I _F | forward current | δ = 1; T _c ≤ 128 °C | | - | - | 6 | А | |
| Static characte | ristics | | | | | | | |
| V_{DC} | DC blocking voltage | | | 650 | - | - | V | |
| Dynamic chara | Dynamic characteristics | | | | | | | |
| Q_C | total capacitive charge | $V_R = 400 \text{ V}; \text{ dI}_F/\text{dt} = 200 \text{ A/}\mu\text{s}; \text{ I}_F \le 6 \text{ A}; $ $T_j = 25 ^{\circ}\text{C}$ | | - | 14 | - | nC | |



650 V, 6 A SiC Schottky diode in TO-220-2 R2P

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------------------------------|--------------------|----------------|
| 1 | K | cathode | mb | |
| 2 | А | anode | | |
| mb | К | mounting base; connected to cathode | TO-220-2 (SOT8021) | K K; mb |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | | | |
|-------------|---------|-------------------------------------------------------------------------------------------------------------------------------------|---------|--|--|
| | Name | Description | Version | | |
| PSC0665K | | Plastic, single-ended package (heatsink mounted, 1 mounting hole) (TO-220-2); 2 leads; 5.08 mm pitch; 15.3 mm x 10 mm x 4.4 mm body | SOT8021 | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PSC0665K | PSC0665K |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|--------------------|---------------------------------|-----------------------------------------------------------------|-----|-----|------|
| V_{RRM} | repetitive peak reverse voltage | T _j = 25 °C | - | 650 | V |
| dv/dt | diode dv/dt ruggedness | 0 ≤ V _R ≤ 480 V | - | 100 | V/ns |
| I _F | forward current | δ = 1; T _c ≤ 128 °C | - | 6 | А |
| I _{FSM} | non-repetitive peak | t _p = 10 μs; square wave; T _c = 25 °C | - | 300 | А |
| | forward current | t _p = 10 ms; half sine-wave; T _c = 25 °C | - | 36 | Α |
| | | t _p = 10 ms; half sine-wave; T _c = 150 °C | - | 30 | А |
| ∫i ² dt | i ² t value | t _p = 10 ms; T _c = 25 °C | - | 6.5 | A²s |
| | | t_p = 10 ms; T_c = 150 °C | - | 4.5 | A²s |
| P _{tot} | total power dissipation | T _c = 25 °C | - | 37 | W |
| Tj | junction temperature | | -55 | 175 | °C |
| T _{amb} | ambient temperature | | -55 | 175 | °C |
| T _{stg} | storage temperature | | -65 | 175 | °C |

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9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|------------------------------------------|------------|-----|-----|-----|------|
| R _{th(j-c)} | thermal resistance from junction to case | | - | 2.9 | 4 | K/W |

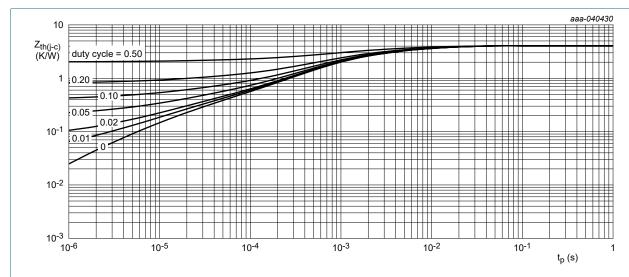


Fig. 1. Transient thermal impedance as a function of pulse duration; maximum values

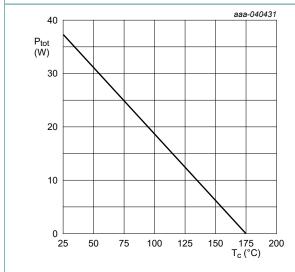


Fig. 2. Power dissipation; maximum values

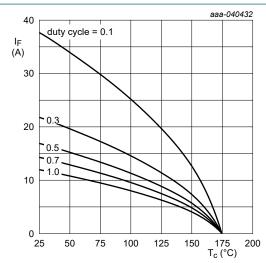


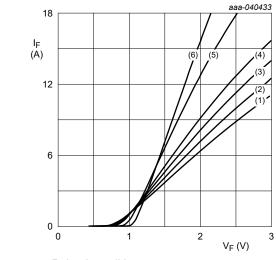
Fig. 3. Forward current as a function of case temperature; maximum values

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10. Characteristics

Table 7. Characteristics

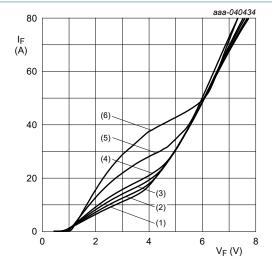
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------|-------------------------|--------------------------------------------------------------------------------------------------------------------------------|-----|------|------|------|
| Static chara | acteristics | | | | | |
| V_{DC} | DC blocking voltage | | 650 | - | - | V |
| V _F | forward voltage | I _F = 6 A; T _j = 25 °C | - | 1.5 | 1.8 | V |
| | | I _F = 6 A; T _j = 150 °C | - | 1.95 | 2.6 | V |
| I _R | reverse current | V _R = 650 V; T _j = 25 °C | - | 1 | 180 | μA |
| | | V _R = 650 V; T _j = 150 °C | - | 10 | 1250 | μA |
| Dynamic ch | naracteristics | | • | | | |
| C _d | diode capacitance | f = 1 MHz; V _R = 1 V; T _j = 25 °C | - | 225 | - | pF |
| Q _C | total capacitive charge | $V_R = 400 \text{ V}; \text{ dI}_F/\text{dt} = 200 \text{ A/}\mu\text{s}; \text{ I}_F \le 6 \text{ A}; $ $T_j = 25 \text{ °C}$ | - | 14 | - | nC |





- (1) $T_j = 175 \,^{\circ}C$
- (2) $T_j = 150 \, ^{\circ}\text{C}$
- (3) $T_j = 125 \,^{\circ}\text{C}$ (4) $T_j = 100 \,^{\circ}\text{C}$
- (5) T_j = 25 °C (6) T_j = -55 °C

Fig. 4. Forward current as a function of forward voltage; typical values

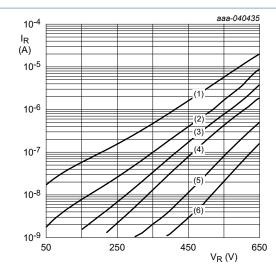


Pulsed condition:

- (1) $T_j = 175 \,^{\circ}C$
- (2) $T_j' = 150 \, ^{\circ}C$
- (3) $T_j = 125 °C$
- (4) $T_j = 100 °C$
- $(5) T_{j} = 25 ^{\circ}C$
- (6) $T_j = -55 \,^{\circ}\text{C}$

Fig. 5. Forward characteristics in surge current as a function of forward voltage; typical values

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Pulsed condition:

(1) $T_j = 175 \, ^{\circ}C$

(2) $T_j = 150 \,^{\circ}\text{C}$ (3) $T_j = 125 \,^{\circ}\text{C}$ (4) $T_j = 100 \,^{\circ}\text{C}$

(5) $T_i = 25 °C$

 $(6) T_i = -55 °C$

Fig. 6. Reverse current as a function of reverse voltage; typical values

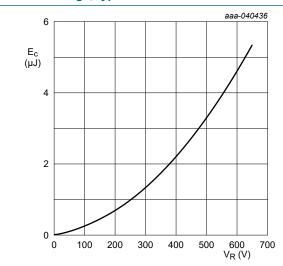
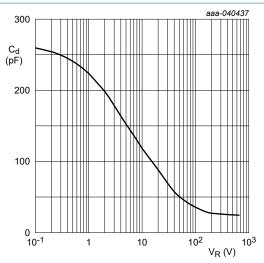
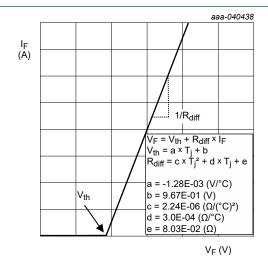


Fig. 8. Capacitance stored energy as a function of reverse voltage; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ °C}$

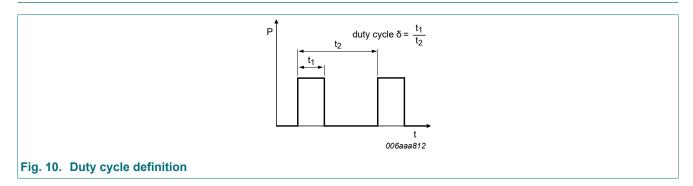
Fig. 7. Diode capacitance as a function of reverse voltage; typical values



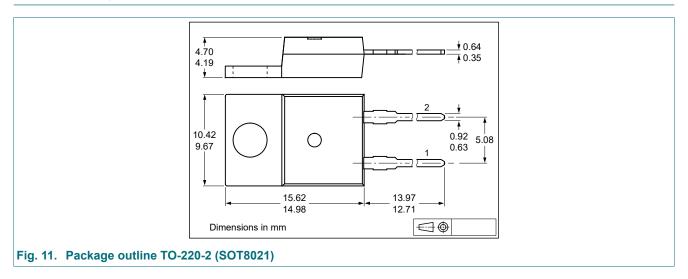
Simplified forward characteristics mode

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11. Test information



12. Package outline



650 V, 6 A SiC Schottky diode in TO-220-2 R2P

13. Revision history

Table 8. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | | | |
|----------------|--------------|-------------------------------------------|---------------|--------------|--|--|--|
| PSC0665K v.2 | 20240819 | Product data sheet | - | PSC0665K v.1 | | | |
| Modifications: | Thermal Chai | Thermal Characteristics: Figure 3 adapted | | | | | |
| PSC0665K v.1 | 20240724 | Product data sheet | - | - | | | |

14. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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- [2] The term 'short data sheet' is explained in section "Definitions".
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